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Prolonged and efficient near-infrared photoluminescence of a sensitized organic ytterbium-containing molecular composite†

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Organic prolonged luminescent materials have attracted attention with various candidates reported providing both UV and visible emission for applications in bio-imaging, light storage, security, etc. However, there is a lack of prolonged near-infrared (NIR) emitting materials, which are highly desirable for many of the proposed applications. NIR-emitting organic lanthanide(III) molecules have suitable wavelengths, but all of them are unsuitable for persistent luminescence due to weak sensitization and the restricted intrinsic ion radiative lifetimes. Herein, this paper demonstrates efficiently sensitized organic Yb(III) compounds with prolonged emission lifetimes up to ~ 0.3 s at 1 μ m, far exceeding the intrinsic Yb³⁺ emission lifetime of ~ 1 ms. The dynamic equilibrium is studied to demonstrate that this prolonged emission is caused by energy transfer from long-lived organic triplet excitons. Experiment and simulation results suggest a new route to develop bright and ultralong-lived 1 µm emitting materials that could be coupled with other existing organic persistent luminescence materials to shift their emission in to the infrared.

There has been considerable interest in the engineering of interor intra-molecular interactions to trap triplet excitons and to use this to demonstrate organic prolonged phosphorescence. This to demonstrate organic prolonged phosphorescence. This is of triplet excitons in organics mainly result from inter-system crossing (ISC) with a small energy separation from the triplets, the reported phosphoresce usually only red-shifts in the visible, e.g. to $\sim\!500$ nm to 600 nm compared to UV-visible fluorescence centred at a wavelength of $\sim\!300$ nm to 400 nm. However, this UV-visible luminescence is not ideal for many of the proposed applications and NIR light, at a wavelength of $\sim\!1~\mu m$ (energy of Organic Yb(m) materials with an organic chromophore that strongly absorbs light to sensitize Yb³⁺ ions can give bright and sharp 1 µm emission under low-power photoexcitation. Various organic Yb(m) complexes or hybrid organic-conjugated Yb³⁺-doped nanoparticles have been demonstrated to provide sensitized Yb³⁺ luminescence. ^{16,17} However, a general problem is that Yb³⁺ emission can be severely quenched by high-energy organic vibrations, *e.g.* C–H, N–H or O–H bonds, and this causes luminescence lifetimes as short as nanoseconds to microseconds with poor efficiencies of <0.1%. ^{18,19} Even though there are effective protective methods to eliminate quenching, the sensitized Yb³⁺ emission lifetime is capped by the intrinsic radiative lifetime which is usually shorter than 2 ms and far from the demands of persistent PL.

Our approach utilizes an organic chromophore to sensitize an organic Yb($\rm III$) molecule in a molecular composite thin film. The organic Yb($\rm III$) molecule we use is a chelate, Yb(F-TPIP)₃ that has a Yb³⁺ ion incorporated with tetrakis-(pentafluorophenyl)imidodiphosphinate, F-TPIP⁻ ligands, and it is inert to visible light.²⁰ The organic chromophore we employ is the zinc salt of 2-(tetrafluoro-2-hydroxyphenyl)tetrafluorobenzothiazole, Zn(F-BTZ)₂, which has strong absorption of blue light.²¹ The chemical properties of the two individual materials have been well studied in previous work.^{20,21}

The 405 nm light photoexcites $\text{Zn}(\text{F-BTZ})_2$ to give the $\text{Zn}(\text{F-BTZ})_2$ emission broadly spanning from \sim 450 nm to 900 nm and sensitizes the sharp Yb³⁺ emission centred at 975 nm due to the Yb³⁺: $^2\text{F}_{5/2} \rightarrow ^2\text{F}_{7/2}$ transition, shown in Fig. 1. The excitation spectrum for the Yb³⁺ emission recorded at 1005 nm matches features of the $\text{Zn}(\text{F-BTZ})_2$ excitation spectrum at 500 nm, indicating a sensitization effect of $\text{Zn}(\text{F-BTZ})_2$ onto Yb³⁺ excitations (*i.e.* light is being absorbed by the $\text{Zn}(\text{F-BTZ})_2$ and the energy is then transferred to the Yb³⁺ ions from which it is

 $[\]sim$ 1.1 eV), would be preferred in many biological applications, due to the high transmission in biological systems at this wavelength and in anti-counterfeiting applications as NIR is not visible to the naked eye. $^{8-15}$

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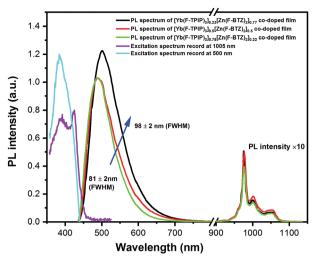


Fig. 1 PL spectra of co-doped films of $[Yb(F-TPIP)_3]_x[Zn(F-BTZ)_2]_{1-x}$ (x = 0.23, 0.5, 0.78) and the excitation spectrum of a co-doped film of [Yb(F-TPIP)₃]_{0.5}[Zn(F-BTZ)₂]_{0.5}. The PL spectra (black, red and green lines) were measured at photoexcitation using a 405 nm laser. The excitation spectra (violet line and light blue line) were recorded at an emission wavelength of 1005 nm and 500 nm, respectively. Both the excitation and PL spectra are optically corrected by the responsivity of photon detectors and spectrometer gratings.

emitted). Previous studies²² have shown abundant triplet excitons in Zn(F-BTZ)₂ and its phosphorescence is centred around 550 nm extending to the NIR beyond 900 nm. This implies the phosphorescence band slightly overlaps the Yb³⁺ absorption which makes the sensitization from the triplet states possible, probably explaining the observation that higher Yb(F-TPIP)₃ doping concentrations selectively quench the phosphorescence to narrow the FWHM of the Zn(F-BTZ)₂ emission (Fig. 1).

Fig. 2(a) shows the time-resolved PL (TRPL) of excited Yb3+ ions recorded at 975 nm. The directly excited Yb3+ emission lifetime is 0.46 \pm 0.12 ms, indicating an internal quantum efficiency of 46%, using a reported intrinsic Yb3+ radiative lifetime of ~ 1 ms in Yb(F-TPIP)₃.²³ The sensitized Yb³⁺ emission lifetime becomes distinctly longer than those obtained by direct excitation into the Yb^{3+} : ${}^2F_{5/2}$ level. Four lifetimes are obtained by fitting with their component percentages. The shortest lifetime (τ_1) of 0.22 \pm 0.11 ms with a component percentage of 6.8% is believed to result from Yb3+ ions that are close to residual quenching centres in the film. The longer lifetime (τ_2) of 0.68 \pm 0.15 ms (24.83%) corresponds to Yb³⁺ ions distant from quenching centres. The information about quenching centres and protective techniques is discussed in the ESI.† These demonstrate that the film contains at least two quenching environments, which lead to corresponding internal quantum efficiencies (IQEs) of 21% and 68%, respectively. Interestingly, the lifetime (τ_3) of 2.22 \pm 0.5 ms (26.59%) and the longest lifetime (τ_4) of 10.2 \pm 1.5 ms (45.7%) are considerably prolonged compared to that for direct excitation and exceed the intrinsic Yb³⁺ radiative lifetime (1 ms). Also, these two prolonged lifetimes are comparable to the long phosphorescence lifetimes of 2.2 \pm 0.4 ms and 11.9 \pm 2.7 ms for the triplet emission at 600 nm (used to reduce the singlet

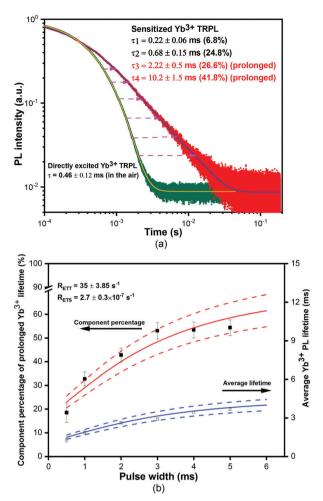


Fig. 2 (a) Directly excited and sensitized time-resolved room-temperature PL spectra of the co-doped film of [Yb(F-TPIP)₃]_{0.5}[Zn(F-BTZ)₂]_{0.5}. The green dots show the directly excited TRPL of the composite film and the red dots show the sensitized TRPL. The orange and blue curves are obtained by fitting the decay traces using exponential decay functions. (b) The component percentages of the prolonged Yb3+ PL lifetimes (solid squares) and the average lifetime of Yb3+ PL (open squares) evolved with photoexcitation pulse widths. The simulated traces for the component percentages and the average Yb3+ PL lifetimes are presented by a red and blue curve, respectively. The error bars of the simulation are given by the dashed lines.

contribution to the decay curve) (Fig. S7 in the ESI†), which implies that energy transfer from the triplets is probably responsible.

To further investigate those prolonged Yb³⁺ emission lifetimes, we varied the pulse-width of a 405 nm laser photoexcitation to manipulate the percentages of the four lifetime components, shown in Fig. 2(b). With a longer pulse width, the population of triplet states around each Yb(F-TPIP)₃ molecule will accumulate to increase the probability to sensitize the Yb3+ ion. Consequently, the total percentage of the prolonged lifetimes of τ_3 and τ_4 , which appear to be relevant to triplet states, increases with longer pulse widths. The increase in the total percentage makes the average lifetime for the obtained Yb3+ emission become longer with extending pulse width. We resolved a set of rate equations to understand the relationship between the

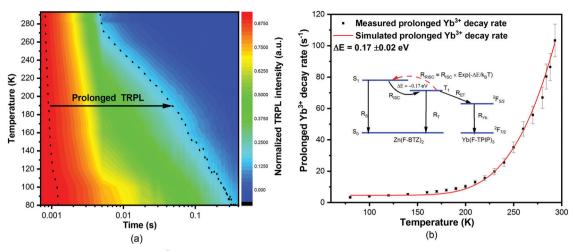


Fig. 3 (a) Temperature dependent sensitized Yb $^{3+}$ TRPL of a co-doped film of [Yb(F-TPIP) $_3$] $_{0.5}$ [Zn(F-BTZ) $_2$] $_{0.5}$ at 975 nm. (b) The measured and simulated temperature-dependent prolonged Yb $^{3+}$ decay rates, which resulted from the introduction of a reverse ISC process into the analytical solution of the rate equations shown in the ESI.†

prolonged Yb³⁺ excitations and triplet states. The construction and deduction of rate equations contain two different time regimes. More details can be found in the ESI.†

The calculation shows that the decay rate for the Yb³⁺: ²F_{5/2} level is a combination of both the triplet decay rate and the intrinsic decay rate of excited Yb $^{3+}$ ions. The $e^{-(R_{ETT}+R_T)\times t_2}$ term (see eqn (S17) in the ESI†) is a decay process for the Yb³⁺ emission that follows the decay rate of the Zn(F-BTZ)2 triplet states. This explains why those prolonged Yb³⁺ emission lifetimes are similar to the persistent phosphorescence lifetimes of the triplet states. As mentioned above, the presence of either Yb(F-TPIP)₃ or Y(F-TPIP)₃ makes no difference to the phosphorescence lifetimes within the range of the experimental error bars. Hence, it is reasonable to use the maximum value of the error bars to estimate the ET rate, which is $R_{\rm ETT} = \sim 35 \text{ s}^{-1}$ (see Fig. S7 in the ESI†). Moreover, the calculation can give the average Yb3+ emission lifetime as a function of the photoexcitation pulse width which is shown as the solid lines in Fig. 2(b), with the calculated time-resolved component percentage of the prolonged Yb³⁺ emission lifetime. The simulation is seen to match the experimental data.

We have used the spectral overlap integral between the triplet phosphorescence spectrum and the Yb3+ absorption spectrum to estimate a Förster resonant energy transfer (FRET) rate, R_{FRET} , which is a conventional method to quantify the Förster energy transfer. The detail of the FRET rate calculation can be found in the ESI.† There are always considerable uncertainties in the parameters used in FRET calculations, not least including the donor quantum yield, orientation factor and the donor-acceptor separation. However, by taking reasonable estimations of the quantum yield as 10%, and the donoracceptor distance from 7 Å (the radius of single Yb(F-TPIP)₃ molecule) to 10 Å (the maximum working distance of FRET),²⁰ the calculated $R_{\rm FRET}$ varies from 64 s⁻¹ to 5 s⁻¹, which are in agreement with our $R_{\rm ETT}$. It is noted that eqn (S21) and (S22) in the ESI† indicate the quantum yield of the energy donor Q_D would only linearly scale the value of R_{FRET} . Hence, as limited

by the maximum and minimum value of Q_D , the value of R_{FRET} is consistent with R_{ETT} to within one order of magnitude.

We present two possible processes to explain the prolonged Yb³⁺ excitations. Firstly, since the low ET rate keeps triplet excitons long-lived, if an excited Yb³⁺ ion relaxes to the ground state, it is possible for a neighbouring triplet exciton to re-excite that de-excited Yb³⁺ ion. Also, long-lived triplet excitons can diffuse *via* intermolecular interactions among Zn(F-BTZ)₂ molecules to reach such an Yb³⁺ ion. These two routes maintain the population level of excited Yb³⁺ ions to overcome the intrinsic Yb³⁺ decay rate.

We have also measured the temperature dependent sensitized-Yb³⁺ TRPL at 975 nm in a co-doped film of [Yb(F-TPIP)₃]_{0.5} [Zn(F-BTZ)]_{0.5}. The contour-colour display of the spectra is shown in Fig. 3(a). It can be clearly seen that prolonged Yb3+ emission becomes dominant with components of 334.5 \pm 30.1 ms (87.9%) with 74.4 \pm 5.9 ms (11.3%) at 80 K. The values of the fitted lifetimes and their component percentages are shown in Table S3 (ESI[†]). This prolonged Yb³⁺ PL implies that a triplet quenching process is suppressed at low temperature. We believe this process is thermally activated reverse-intersystem-crossing (RISC). Using the simple rate model shown in the inset to Fig. 3(b) we can fit the data and obtain an energy gap of 0.17 \pm 0.02 eV between the triplet state (T_1) and the singlet state (S_1) of $Zn(F-BTZ)_2$. The fitted energy gap is of the order of the singlet-triplet energy separation in the chromophore. The result implies the use of a chromophore material with a larger singlet-triplet energy separation would provide a route to exceptionally prolonged room temperature Yb³⁺ PL lifetimes using this approach.

Conclusions

In summary, composite thin films are fabricated to produced sensitized Yb^{3+} 1 μm photoluminescence. Sensitized time-resolved photoluminescence measurement indicates that the sensitized Yb^{3+} lifetime is prolonged to exceed its intrinsic

lifetime. Simulation of excited state dynamic suggests the prolonged lifetime is due to the energy transfer from long-lived triplet. Additionally, our work demonstrates a potential route to develop bight and ultra-long lived 1 µm emitting material that could be coupled to some known persist luminescence materials to shift their emission wavelength to infrared.

Methods

Details of methods, materials and optical measurement techniques can be found in the ESI.† HFTPIP and HFBTZ ligands were supplied by Chromosol Ltd. YbCl₃·(H₂O)₆ (metals basis 99.99% purity) was purchased from Alfa Aesar. Yb3+ salt and the HFTPIP ligand were reacted in methanol:ethanol solution to produce Yb(F-TPIP)3 precipitates. KOH and the HFBTZ ligand were used to form KFBTZ and then reacted with a Zn^{2+} salt to precipitate $Zn(F-BTZ)_2$. The reaction condition to make Yb(F-TPIP)3 and Zn(F-BTZ)2 are routine and have been reported.20,21 A train vacuum purification system was used to purify the materials before the use. The display of Fig. 2(a) uses logarithmic scales for both the x-axis and y-axes, to fully visualize the details of the decay curves over a wide range time regime, which cannot be seen with a linear x-axis. The composite of two materials in thin films are fabricated using a co-evaporation technique using a Kurt J. Lesker SPECTROS deposition system in a 10 K-class cleanroom. A Hamamatsu R5509-72 nitrogen-cooled detector with a Horiba Triax 550 spectrometer was used to collect and detect photoluminescence signals. Multiple exponential functions are used to fit time-resolved decay curves to obtain TRPL lifetimes. All the film samples were covered by a 100 nm layer of thermally grown aluminium film. The low temperature measurements were taken using an Oxford Instrument continuous flow cryostat.

Conflicts of interest

There are no conflicts to declare.

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